

IS6051



## LOW INPUT CURRENT INFRA-RED EMITTING DIODE & LIGHT ACTIVATED SCR

### APPROVALS

- UL recognised, File No. E91231

### DESCRIPTION

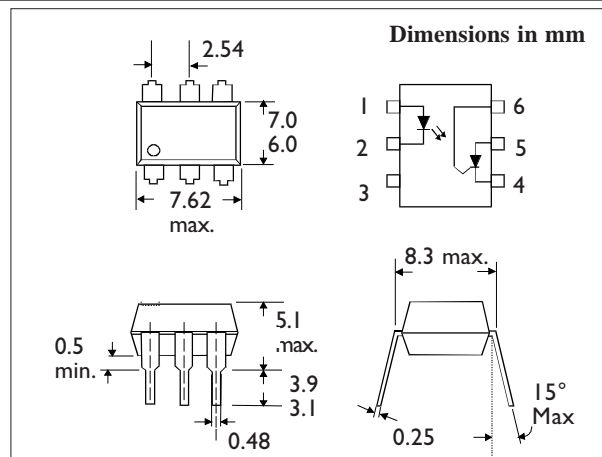
The IS6051 is an optically coupled isolator consisting of infrared light emitting diode and a light activated silicon controlled rectifier in a standard 6pin dual in line plastic package.

### FEATURES

- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- High Surge Anode Current (5.0 A)
- High Blocking Voltage (400V\*1)
- Low Turn on Current (5mA typical)
- All electrical parameters 100% tested
- Custom electrical selections available

### APPLICATIONS

- 10A, T<sup>2</sup>L compatible, Solid State Relay
- 25W Logic Indicator Lamp Driver
- 400V Symmetrical transistor coupler



### ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise specified)

Storage Temperature	-55°C to + 150°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

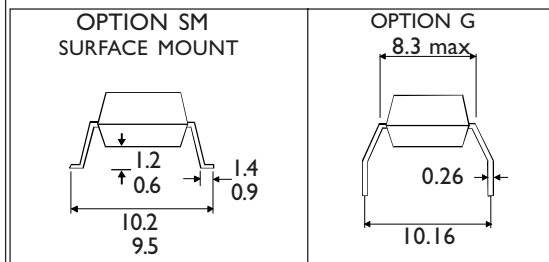
### INPUT DIODE

Forward Current	60mA
Forward Current (Peak) (1µs pulse, 300pps)	3A
Reverse Voltage	6V
Power Dissipation	100mW

### DETECTOR

Peak Forward Voltage IS605	400V*1
Peak Reverse Gate Voltage	6V
RMS On-state Current	300mA
Peak On-state Current (100µs, 1% duty cycle)	10A
Surge Current (10ms)	5A
Power Dissipation	300mW

\*1 IMPORTANT : A resistor must be connected between gate and cathode (pins 4 & 6) to prevent false firing ( $R_{GK} < 56k\Omega$ )



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**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ )		1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse Voltage ( $V_R$ )	3			V	$I_R = 10\mu\text{A}$
Output (note 2)	Peak Off-state Voltage ( $V_{DM}$ )	400			V	$R_{GK} = 10\text{k}\Omega, I_D = 2\mu\text{A}$
	Peak Reverse Voltage ( $V_{RM}$ )	400			V	$R_{GK} = 10\text{k}\Omega, I_D = 2\mu\text{A}$
	On-state Voltage ( $V_{TM}$ )		1.1	1.3	V	$I_{TM} = 300\text{mA}$
	Off-state Current ( $I_{DM}$ )			2	$\mu\text{A}$	$R_{GK} = 10\text{k}\Omega, I_F = 0,$ $V_{DM} = 400\text{V}$
	Reverse Current ( $I_R$ )			2	$\mu\text{A}$	$R_{GK} = 10\text{k}\Omega, I_F = 0,$ $V_{DM} = 400\text{V}$
Coupled	Input Current to Trigger ( $I_{FT}$ ) (note 2)			3	mA	$V_{AK} = 100\text{V}, R_{GK} = 27\text{k}\Omega$
	Turn on Time ( $t_{on}$ )			50	$\mu\text{s}$	$R_{GK} = 27\text{k}\Omega, I_F = 30\text{mA},$ $V_{AK} = 20\text{V}, R_L = 200\Omega$
	Coupled dv/dt, Input to Output (dv/dt)	500			V/ $\mu\text{s}$	
	Input to Output Isolation Voltage $V_{ISO}$	5300			$V_{RMS}$	See note 1
	Input-output Isolation Resistance $R_{ISO}$	7500			$V_{PK}$	See note 1
	Input-output Capacitance $C_f$	$10^{11}$		2	$\Omega$ pF	$V_{IO} = 500\text{V}$ (note 1) $V = 0, f = 1\text{MHz}$

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.